

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION

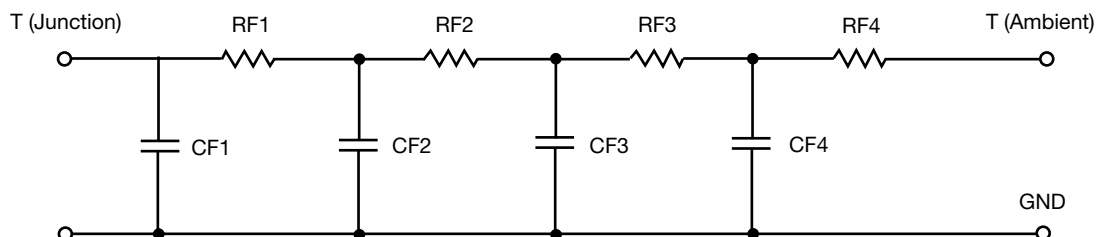


R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient Full Copper (FC)	Case	Ambient Minimum Copper (MC)
RT1	41.7716	N/A	53.5334
RT2	9.8053	N/A	37.0723
RT3	23.9352	N/A	58.5941
RT4	24.4879	N/A	40.8002
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient Full Copper (FC)	Case	Ambient Minimum Copper (MC)
CT1	268.7307 u	N/A	831.5863 u
CT2	560.9886 m	N/A	59.9225 m
CT3	4.6235 m	N/A	4.9132 m
CT4	1.6627	N/A	593.8783 m

Note

N/A indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION

R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient Full Copper (FC)	Case	Ambient Minimum Copper (MC)
RF1	39.7173	N/A	76.2752
RF2	26.0422	N/A	54.0982
RF3	21.2421	N/A	29.6710
RF4	12.9610	N/A	29.9583
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient Full Copper (FC)	Case	Ambient Minimum Copper (MC)
CF1	225.6878 u	N/A	726.5842 u
CF2	2.5206 m	N/A	6.5736 m
CF3	475.7535 m	N/A	105.7789 m
CF4	2.9455	N/A	724.3197 m

Note

N/A indicates not applicable

